

Supporting Information

Graphite@Silicon embedded in Carbon Conformally Coated Tiny SiO₂ Nanoparticles Matrix for High-Performance Lithium-Ion Batteries

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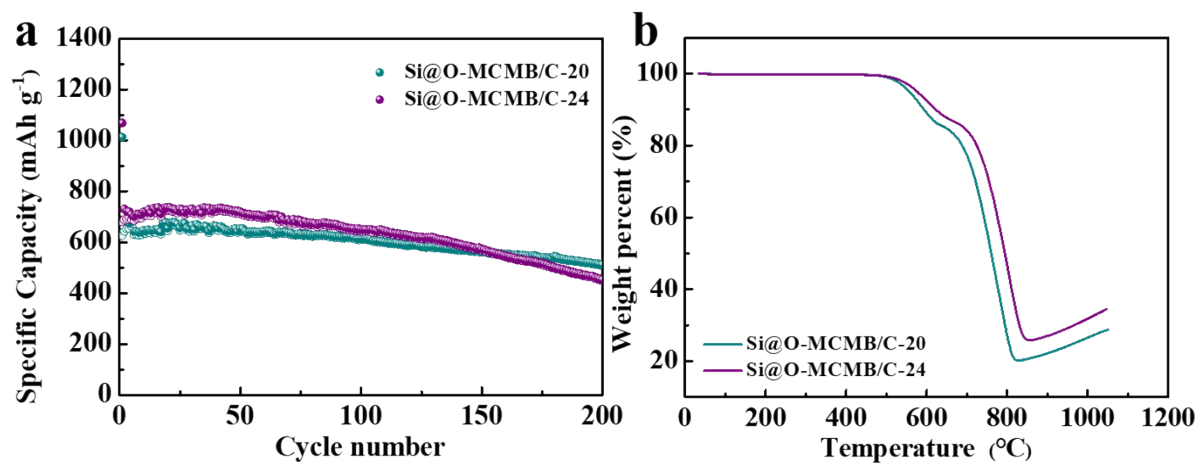


Figure S1 (a) Cycling performances of Si@O-MCMB/C with different Si contents. (b) TGA curves under an oxygen atmosphere, where the Si@O-MCMB/C composites with 20 and 24 wt% Si content are denoted as Si@O-MCMB/C-20 and Si@O-MCMB/C-24.

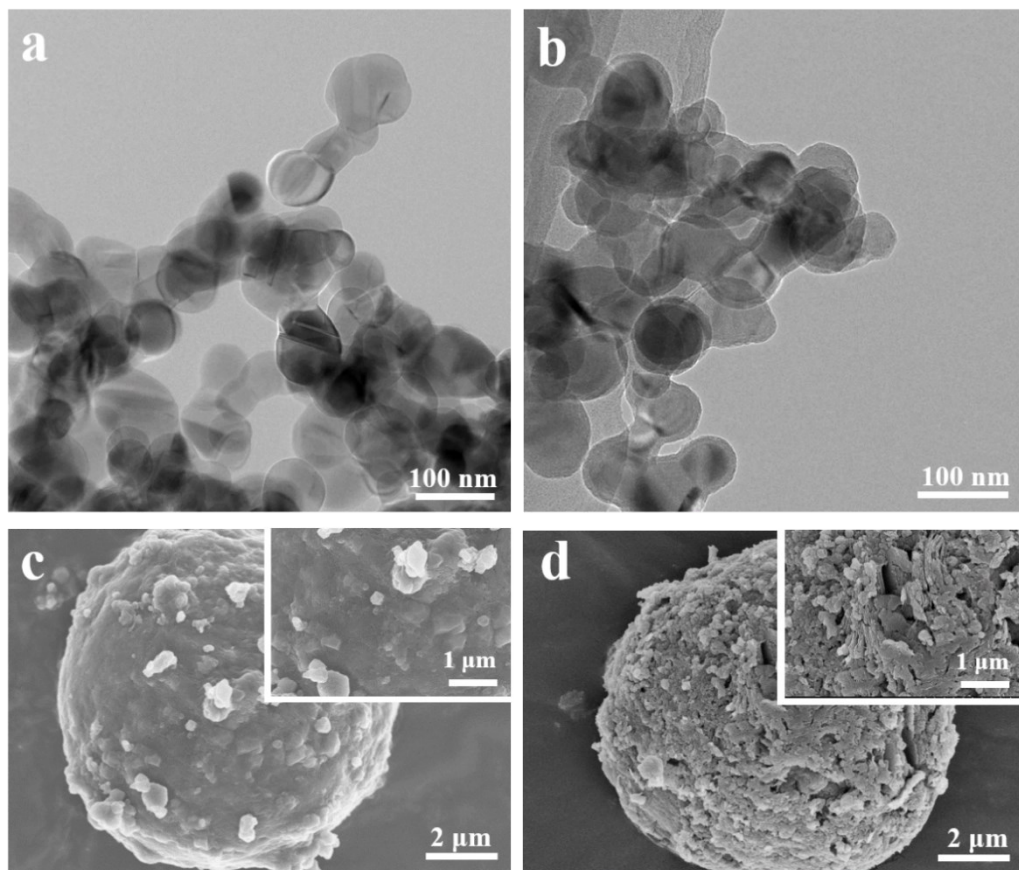


Figure S2 TEM images of (a) pure Si and (b) Si-PDDA. SEM images of (c) graphite and (d) graphite after being treated by mixed acid. A polymer layer is observed for Si-PDDA particles, indicating the successful modification of Si NPs by PDDA. After mixed acid oxidation, the graphite shows a relatively rough surface, which was generated by the positively charged Si-PDDA and negatively charged graphite through electrostatic attraction.

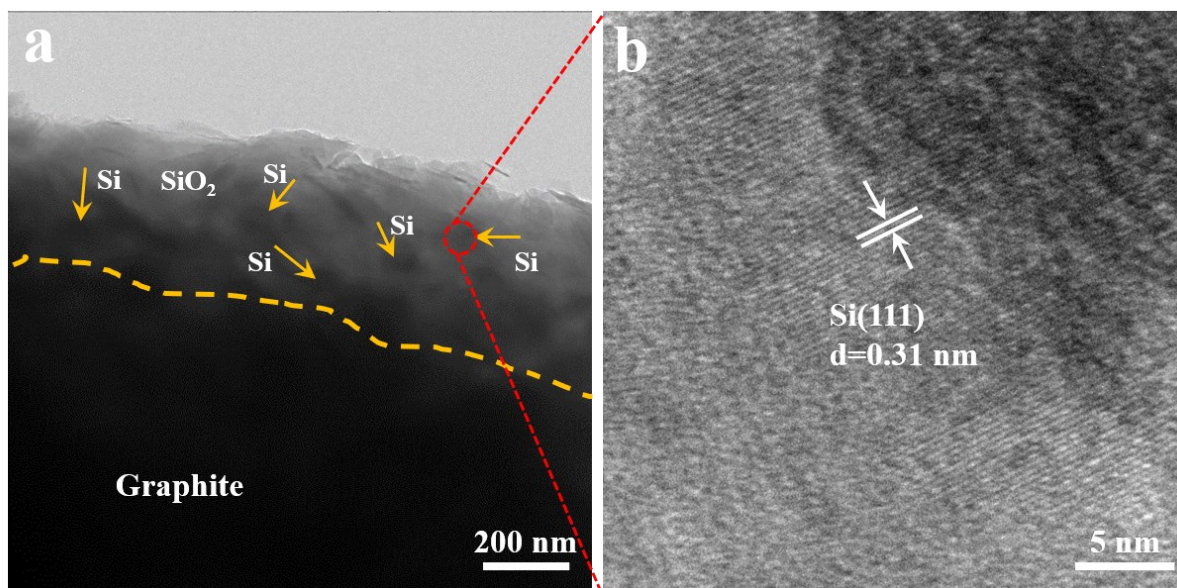


Figure S3 (a) TEM and (b) HRTEM images of G/Si/SiO₂ layer. The TEM images in Figure S3 further verify that the crystalline SiNPs are well encapsulated in the SiO₂ matrix with a thickness of about 400 nm deposited on the graphite skeleton.

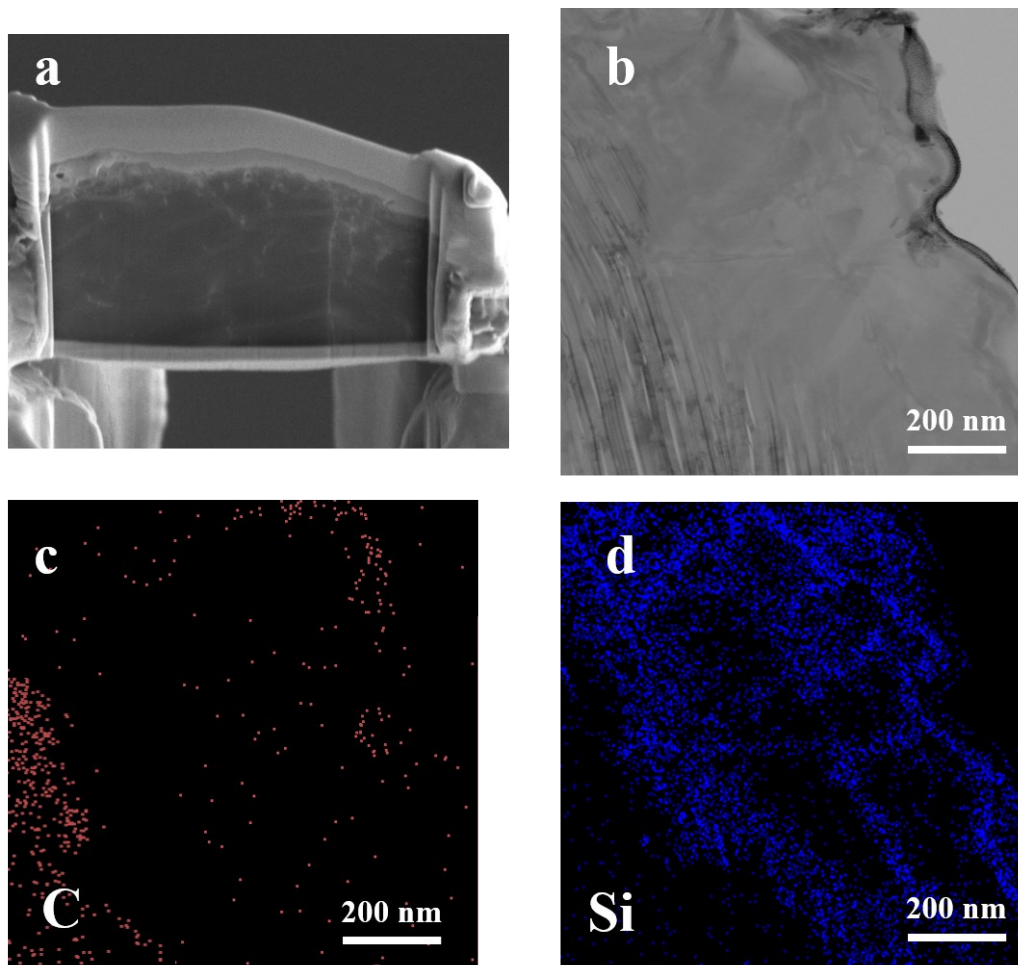


Figure S4 (a) SEM image, (b) TEM and (c and d) EDS of G@Si/SiO₂ layer/C in cross-sectional view.

TEM and corresponding EDS images are conducted after cutting the G@Si/SiO₂ layer/C by Dual-Beam Focus Ion Beam System (FIB). It can be seen that the carbon shell on the outmost layer of the G@Si/SiO₂ layer/C microsphere is isolated from the inner graphite core.

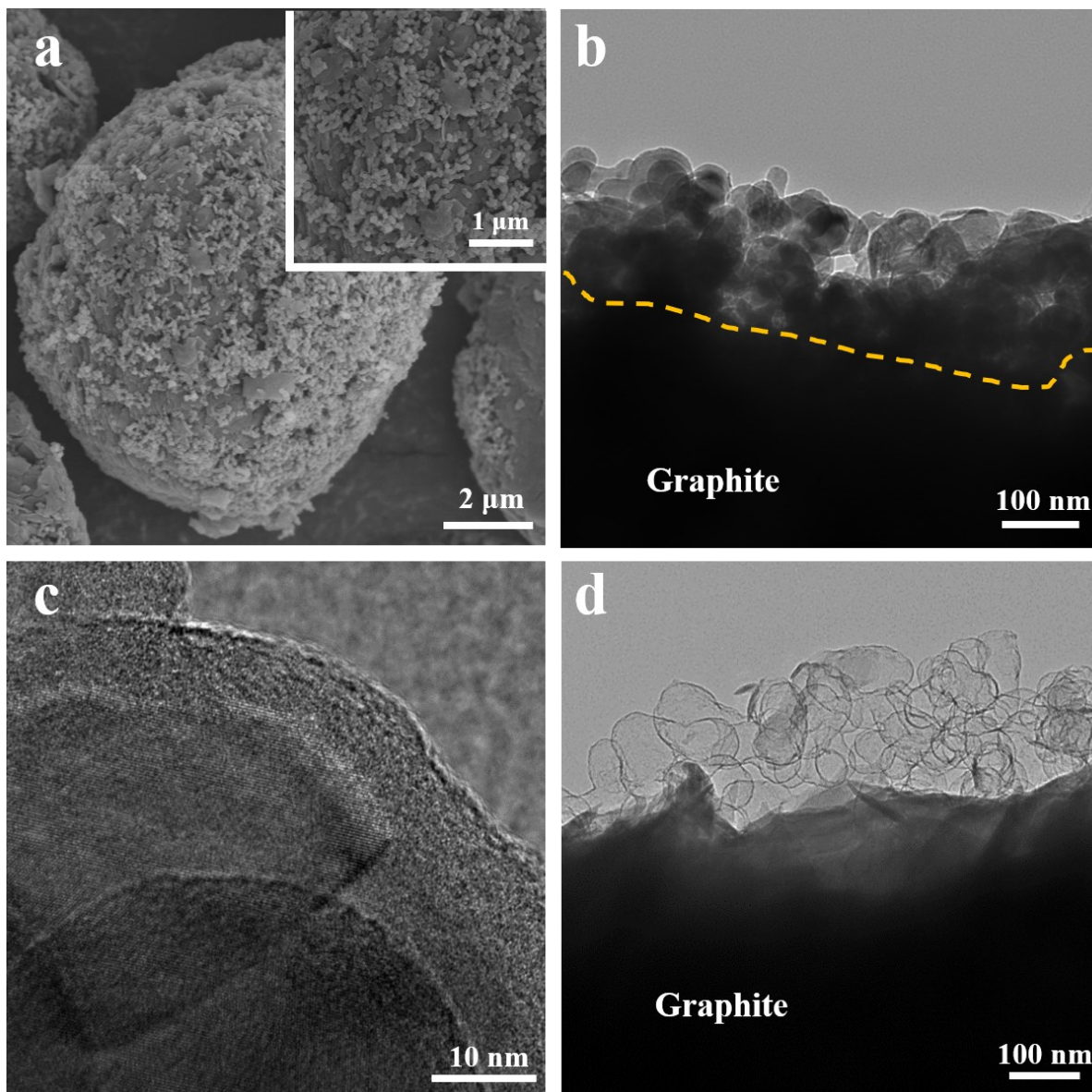


Figure S5 (a) SEM image of G@Si/C. (b) TEM and (c) HRTEM images of G@Si/C. (d) TEM image of G@Si/C after removing Si.

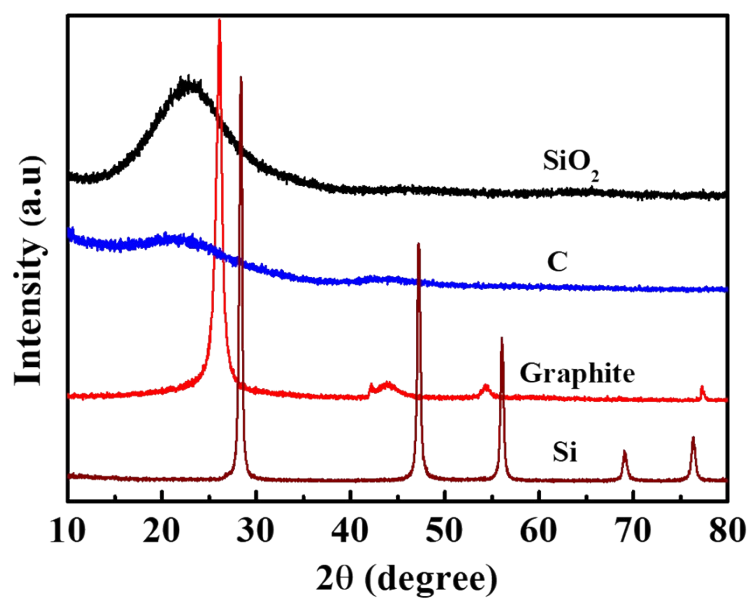


Figure S6 XRD patterns of SiO₂, amorphous carbon, graphite and Si.

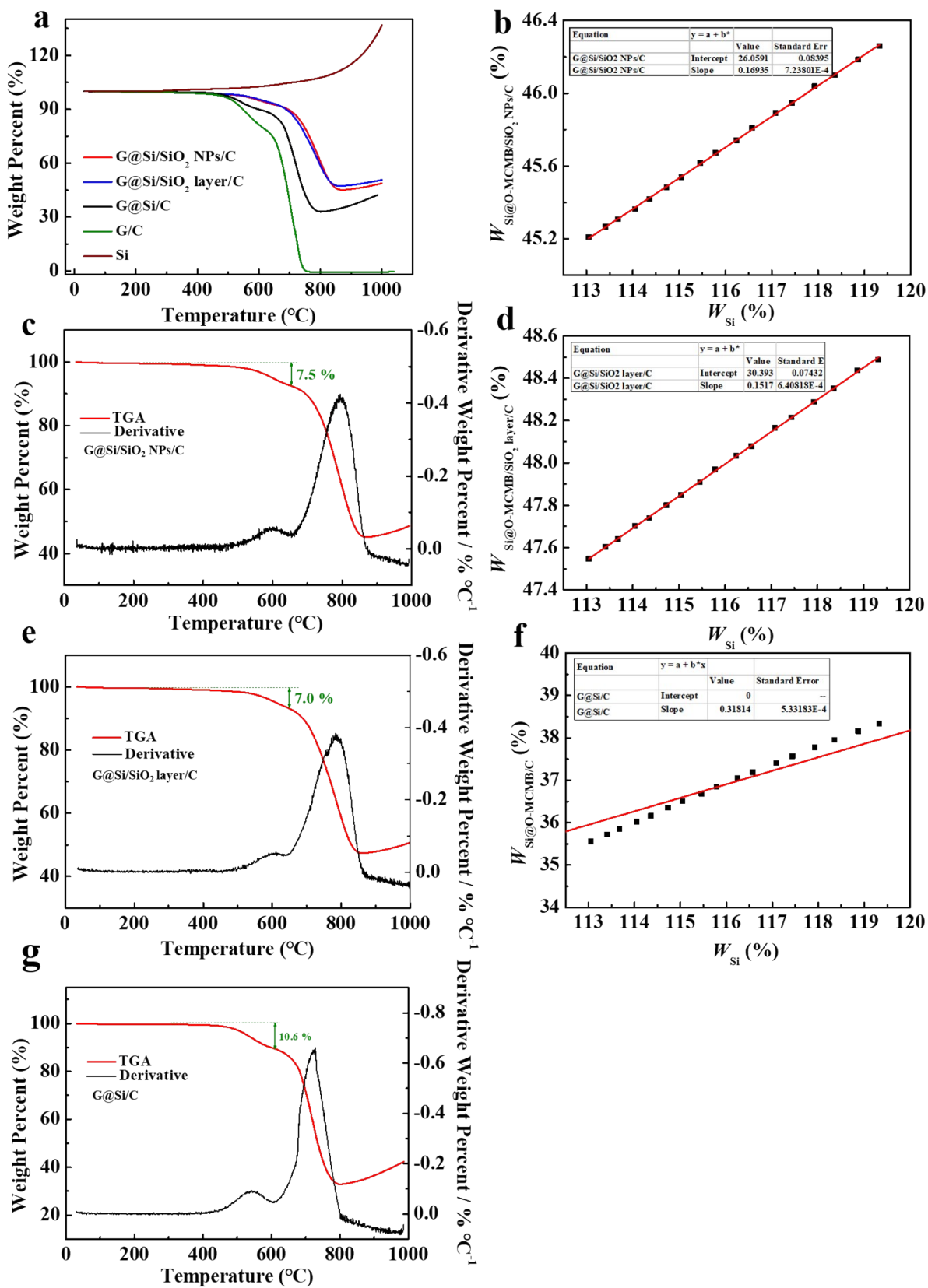


Figure S7 (a) Thermal gravimetric analysis (TGA) curves under the oxygen atmosphere at a heating rate of 10 °C min⁻¹. The relationship between remaining weight percent of (b) G@Si/SiO₂ NPs/C, (d) G@Si/SiO₂ layer/C and (f) G@Si/C, respectively. Weight percent and

derivative weight percentage curves for (c) G@Si/SiO₂ NPs/C, (e) G@Si/SiO₂ layer/C and (g) G@Si/C.

Note: The content of Si and SiO₂ in these composites could be calculated based on the equation:

$W_{Si}x_{Si} + W_{graphite/C}(1-x_{Si}-x_{SiO_2}) + W_{SiO_2} = W_{G@Si/SiO_2\ NPs/C}$ ($W_{G@Si/SiO_2\ layer/C}$ or $W_{G@Si/C}$), where W_{Si} , $W_{G/C}$ and $W_{G@Si/SiO_2\ NPs/C}$ ($W_{G@Si/SiO_2\ layer/C}$ or $W_{G@Si/C}$) represent the remaining weight percent of SiNPs, G/C composites and G@Si/SiO₂ NPs/C (G@Si/SiO₂ layer/C or G@Si/C) composites, W_{SiO_2} is the remaining weight percent of SiO₂, which is constant in all the test temperature ranges, x_{Si} denotes the content of Si. If the G/C combusts completely, in other words, $W_{G/C}$ is equal to 0, x_{Si} and W_{SiO_2} can be obtained from the slopes and intercept of W_{Si} vs. $W_{G@Si/SiO_2\ NPs/C}$, $W_{G@Si/SiO_2\ layer/C}$ or $W_{G@Si/C}$. The linear fitting between W_{Si} and $W_{G@Si/SiO_2\ NPs/C}$, $W_{G@Si/SiO_2\ layer/C}$ or $W_{G@Si/C}$ in the range of 880–930 °C are shown in Figure S6b, d and f. Accordingly, the content of Si and SiO₂ in the G@Si/SiO₂ NPs/C are determined to be 16.9% and 26.1% respectively, while that in the G@Si/SiO₂ layer/C hybrid spheres are 15.2% and 30.4%. In addition, the Si content of the G@Si/C is about 31.8%.

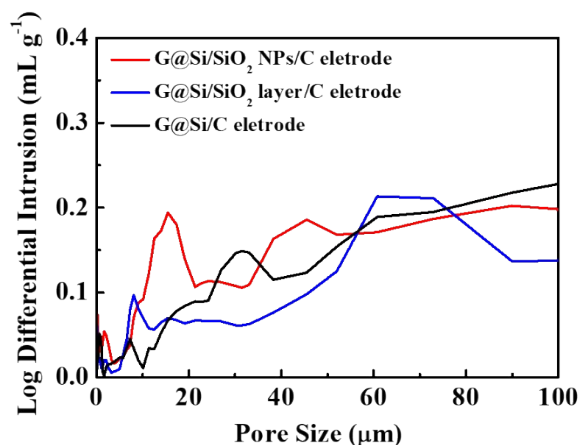


Figure S8 Pore size distribution curves of the different electrodes obtained with MIP.

Mercury intrusion porosimetry (MIP) is used to characterize the pore structures of the as made electrodes. Figure S8 shows that all electrodes have a broad pore size distribution, ranging from about 10 nm to several hundred micrometers. The results of porosity and average pore diameter from MIP are summarized in Table S2. The higher overall porosity and larger pore size are conducive to the fast wetting of the electrodes

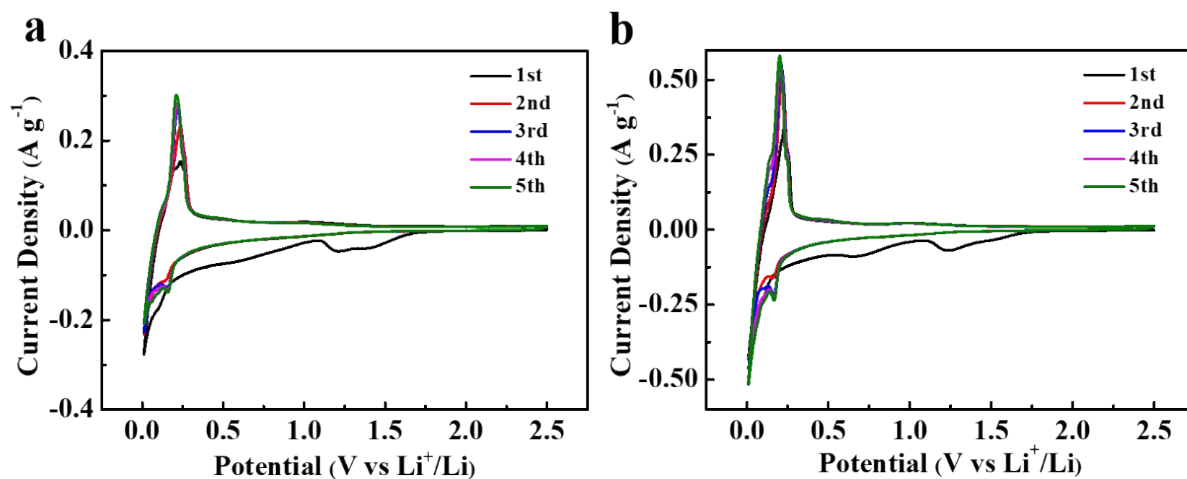


Figure S9 Cyclic voltammetry profiles of (a) G@Si/SiO₂ layer/C and (b) G@Si/C.

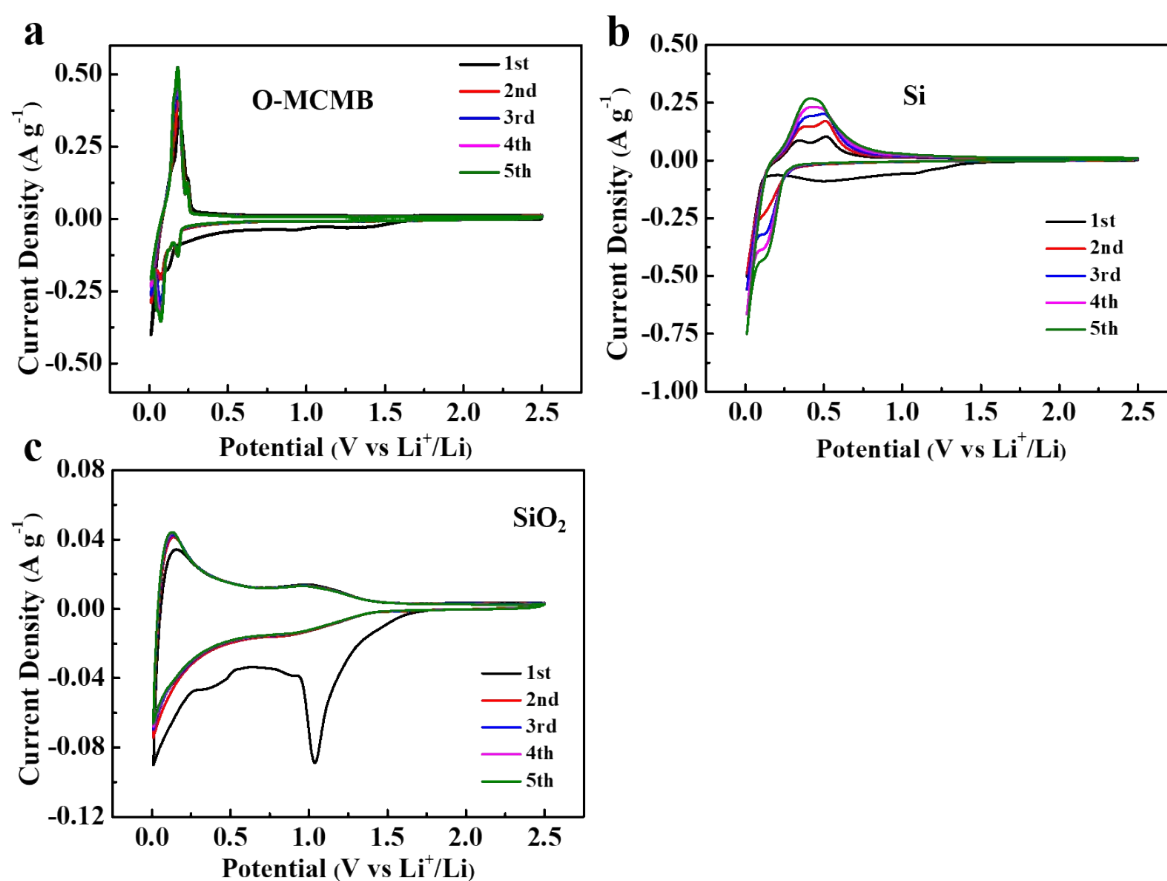


Figure S10 Cyclic voltammetry profiles of (a) graphite, (b) Si and (c) pure SiO₂ electrodes.

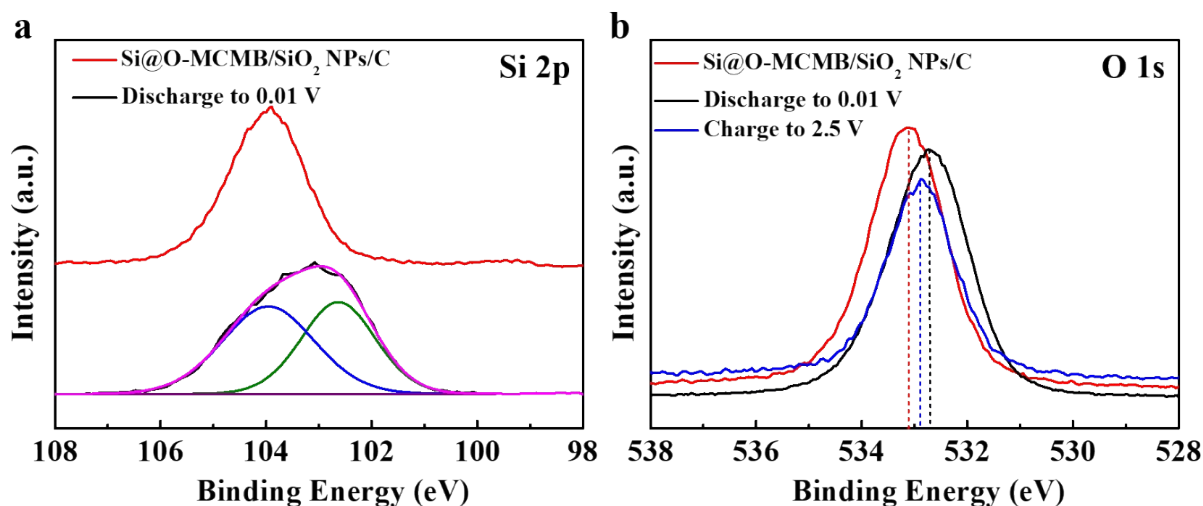


Figure S11 The Si 2p (a) and O 1s (b) XPS spectra of the G@Si/SiO₂ NPs/C before and after cycle.

X-ray photoelectron spectroscopy (XPS) was employed to check the variation of the crystalline structure of SiO₂ during the electrochemical process. As shown in Figure S11, the peak at 103.9 eV is corresponding to the amorphous silica. After discharge, two new peaks appear, the one located at 103.4 eV is assigned to Li₄SiO₄ and the other at 102.0 eV belongs to Li–Si alloy. As expected, the O 1s peak also shifts to low binding energy after discharge. In addition, the peak of O 1s does not fully recover to its previous position, which means that the formation of the Li₄SiO₄ is irreversible.

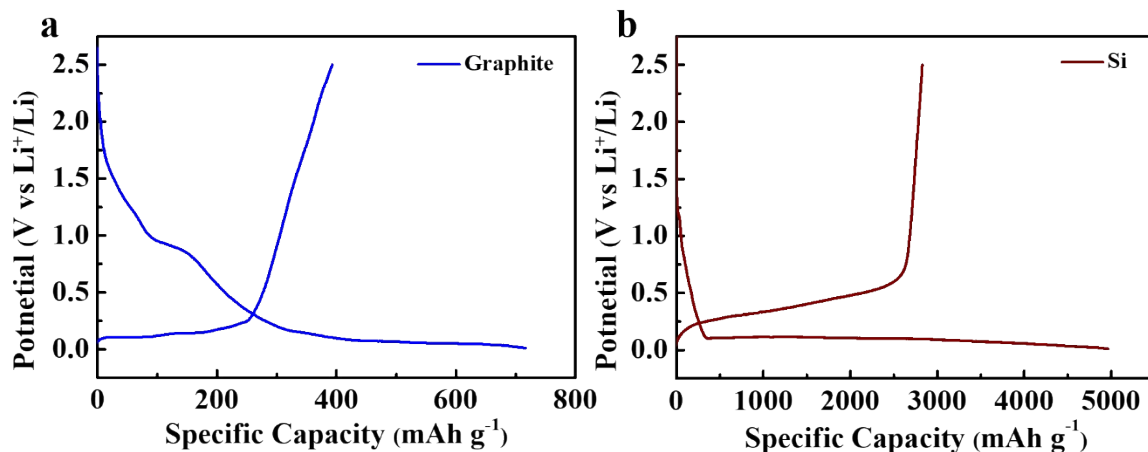


Figure S12 Initial discharge-charge voltage profiles of (a) graphite after treated with mixed acid and (b) Si.

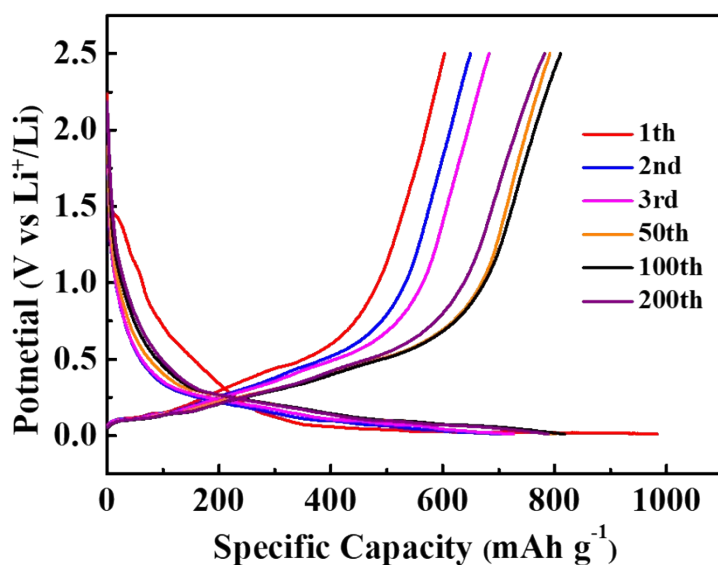


Figure S13 Voltage profiles of the G@Si/SiO₂ NPs/C composites for the 1st, 2nd, 3rd, 50th, 100th, and 200th cycles.

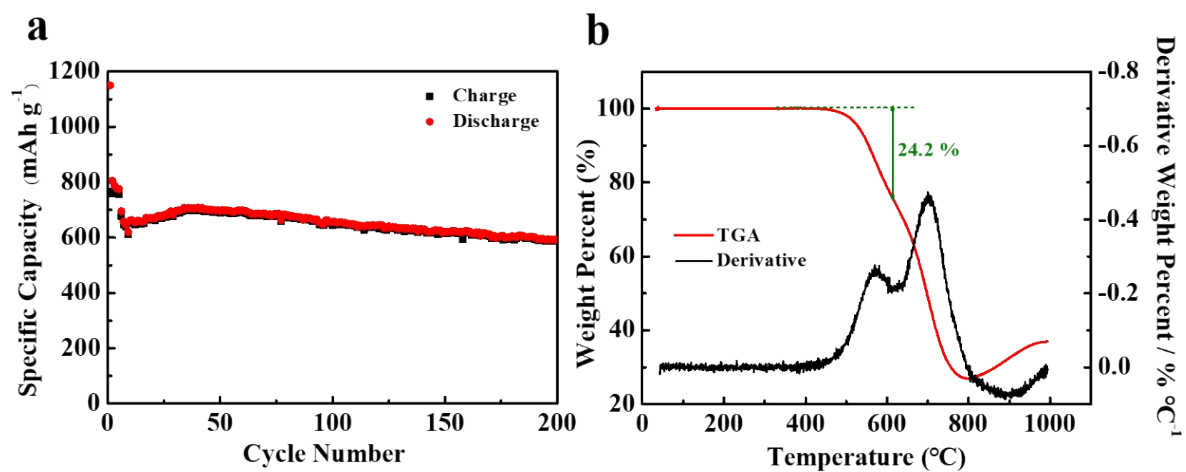


Figure S14 (a) Cycling performance of G@Si/C with a high carbon content of 24.2%. (b) The weight percent and derivative weight percentage curves.

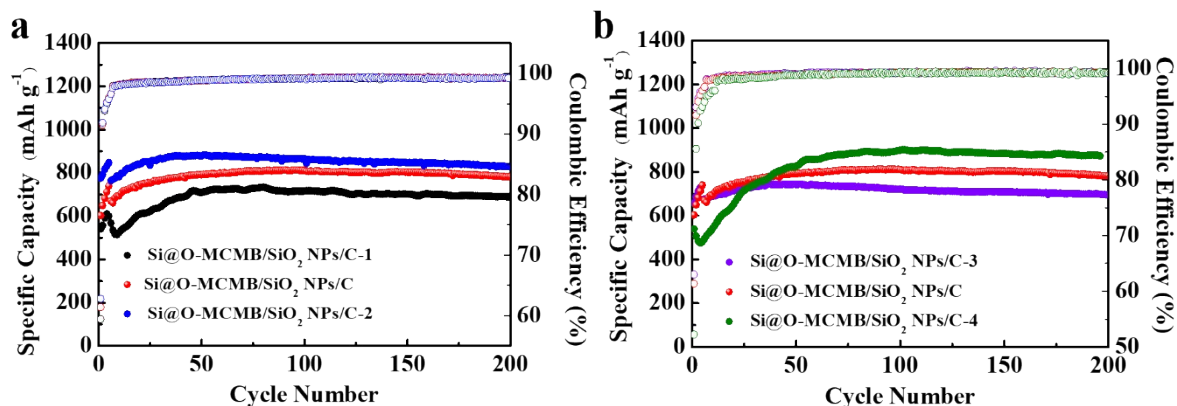


Figure S15 Cycling performances of G@Si/SiO₂ NPs/C with different components.

The G@Si/SiO₂ NPs/C composites with different components are also prepared (Figure S16 and Table S1). When increasing the amount of Si, the G@Si/SiO₂ NPs/C-2 composites show a higher specific capacity of 884 mAh g⁻¹ and a slightly more rapid capacity fading at 200 mA g⁻¹ compared to the G@Si/SiO₂ NPs/C and G@Si/SiO₂ NPs/C-1 composites with the lower amount of Si (Figure S15 a).

As increasing the amount of SiO₂, the specific capacity of G@Si/SiO₂ NPs/C-4 increases to 891 mAh g⁻¹ and the capacity retention is almost 100% after 200 cycles. While too much SiO₂ and too little amorphous carbon prolong the activation time (Figure S15 b).

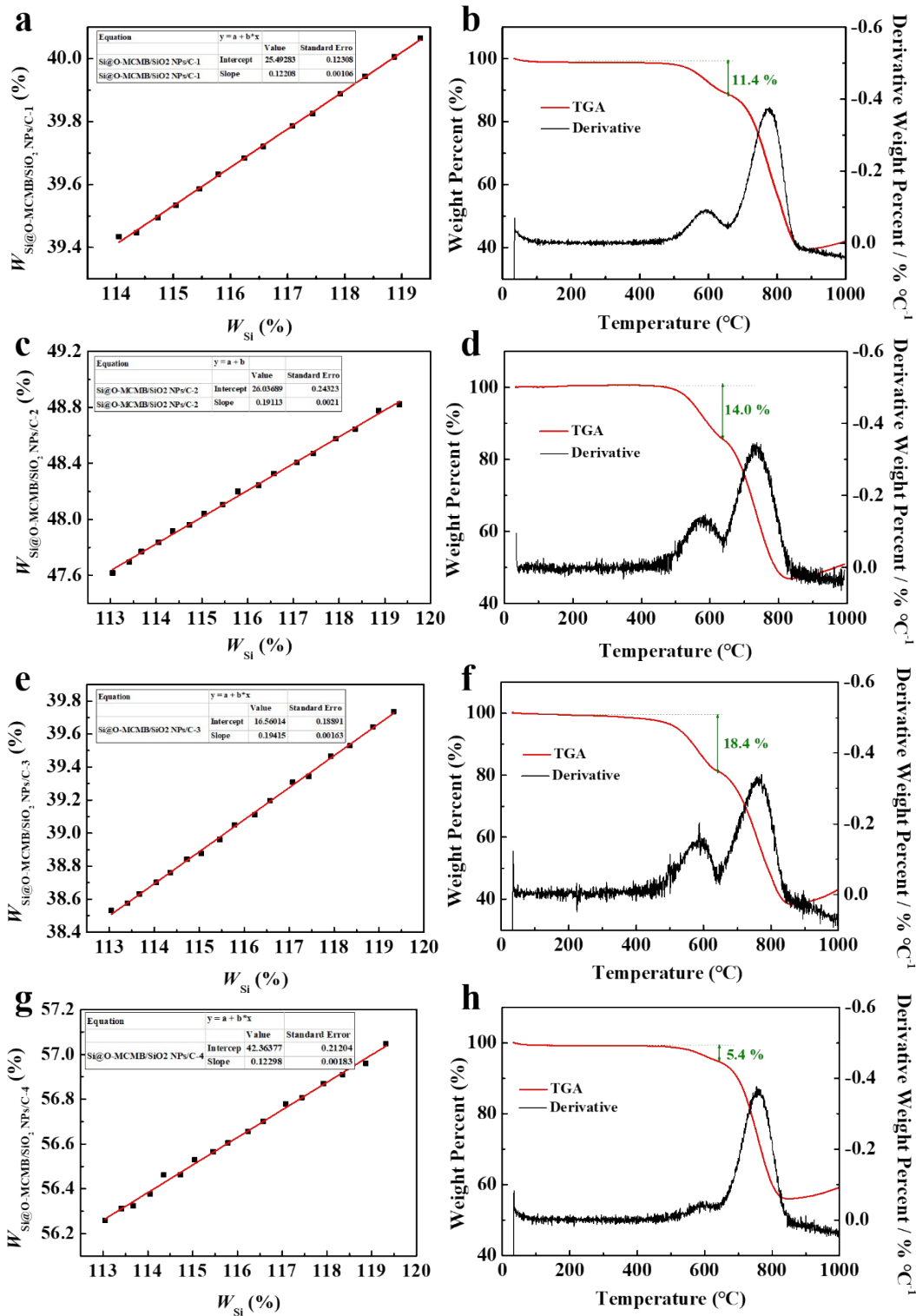


Figure S16 The relationship between remaining weight percent of (a) G@Si/SiO₂ NPs/C-1, (c) G@Si/SiO₂ NPs/C-2, (e) G@Si/SiO₂ NPs/C-3 and (g) G@Si/SiO₂ NPs/C-4, respectively. Weight percent and derivative weight percentage curves for (d) G@Si/SiO₂ NPs/C-1, (e) G@Si/SiO₂ NPs/C-2, (f) G@Si/SiO₂ NPs/C-3 and (h) G@Si/SiO₂ NPs/C-4.

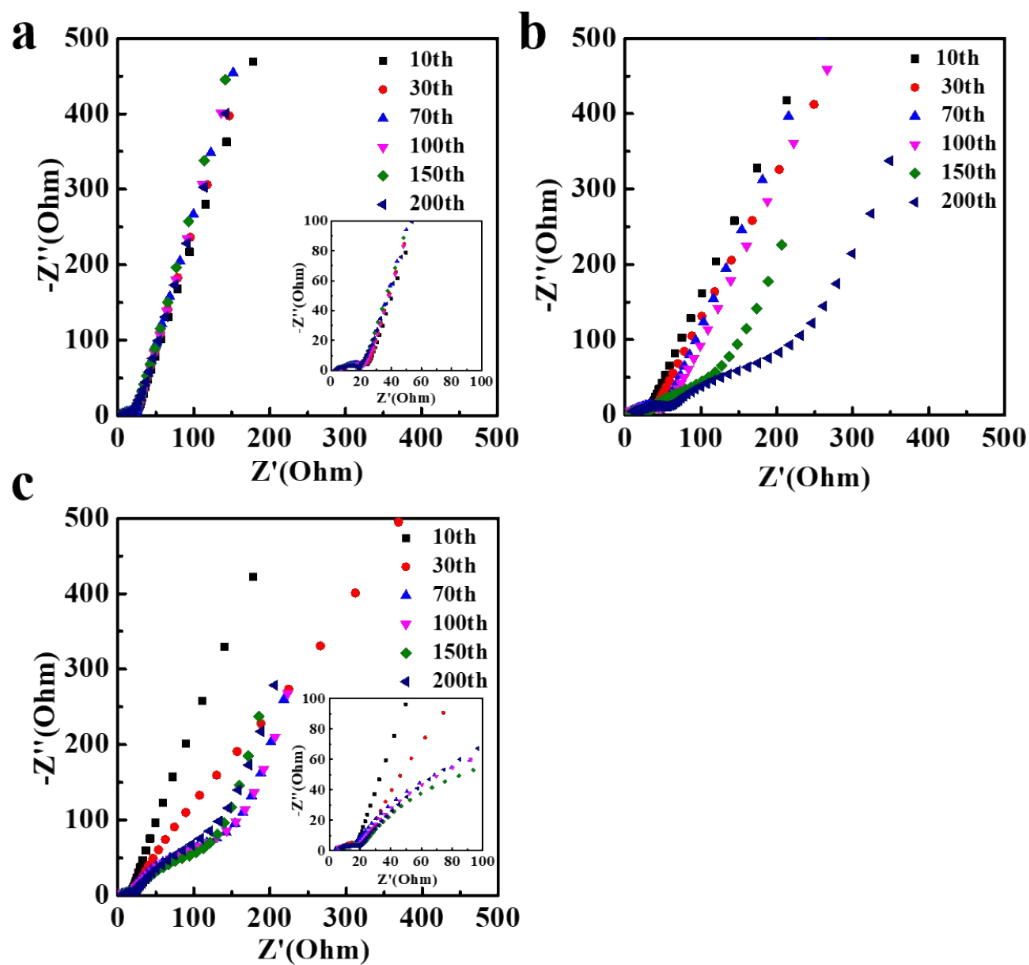


Figure S17 Nyquist plots of the EIS spectra of the (a) G@Si/SiO₂ NPs/C, (b) G@Si/SiO₂ layer/C and (c) G@Si/C electrodes in the delithiation stage after different cycles at 0.5 A g⁻¹.

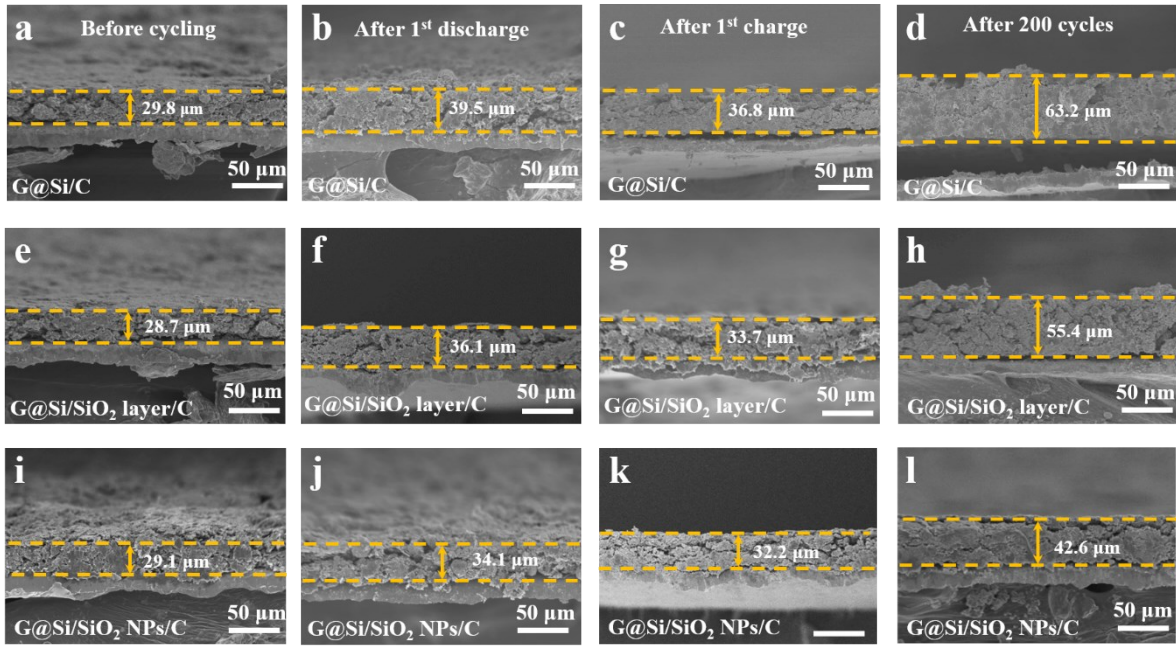


Figure S18 Cross-sectional SEM images of G@Si/C electrodes (a) before cycles, (b) after 1st discharge, (c) after 1st charge and (d) after 200th charge. Cross-sectional SEM images of G@Si/SiO₂ layer/C electrodes (e) before cycles, (f) after 1st discharge, (g) after 1st charge and (k) after 200th charge. Cross-sectional SEM images of G@Si/SiO₂ NPs/C electrodes (i) before cycles, (j) after 1st discharge, (k) after 1st charge and (l) after 200th charge.

After first discharge, the G@Si/SiO₂ NPs/C anode with a thickness of 29.1 μm expands to about 17.2% (34.1 μm) in height, which is much lower than 25.8% for G@Si/SiO₂ layer/C and 32.6% for G@Si/C electrodes. After a subsequent charge process, the thickness of the G@Si/SiO₂ NPs/C composite anode slightly decreased to 32.2 μm, corresponding to 10.7%, which is also a lower value compared with the 17.4% of the G@Si/SiO₂ layer/C and 23.5% of the G@Si/C anode. After a long cycle (200 cycles at the charge state), the G@Si/C electrode exhibits a large thickness increase of 112% with particles delamination. While the G@Si/SiO₂ NPs/C shows the smallest volume expansion (46%) with no obvious variation of the electrode surface after cycles, implying that the conformal coated carbon on SiO₂ NPs in the G@Si/SiO₂ NPs/C can tolerate the volume expansion more effectively than outermost carbon layer in G@Si/SiO₂ layer/C during the lithiation/delithiation process, thereby retaining structural stability after long cycling.

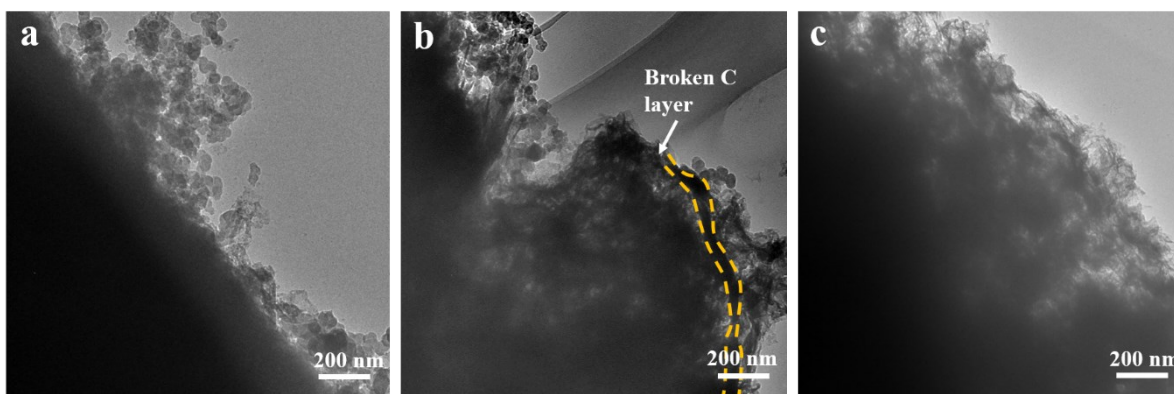


Figure S19 TEM of the (a) G@Si/C, (b) G@Si/SiO₂ layer/C and (c) G@Si/SiO₂ NPs/C electrodes after 200 cycles at 0.5 A g⁻¹.

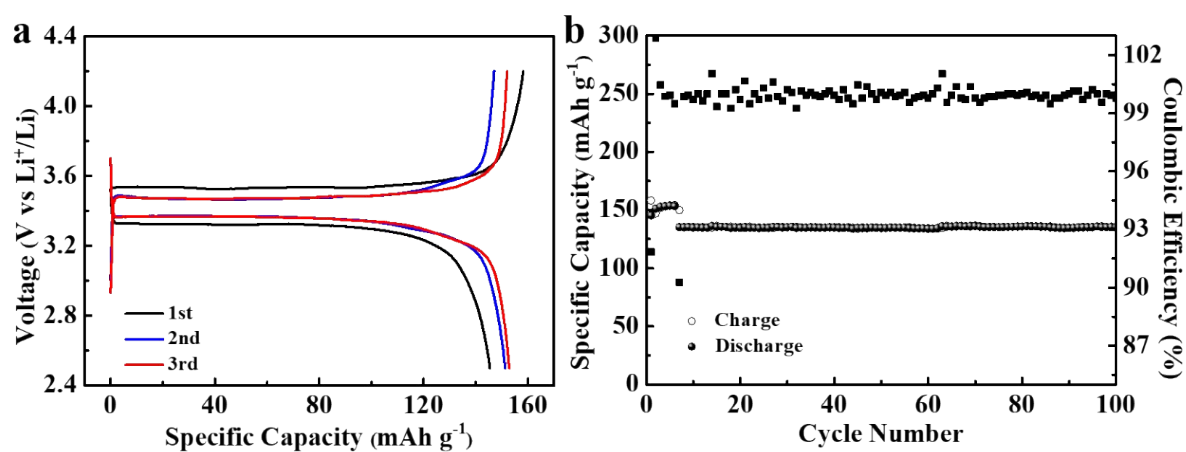


Figure S20 (a) Voltage profiles of LFP half cells. (b) The Cycling performance of the LFP half cells tested at 0.2 C for the first five cycles and 1 C for the later cycles.

Table S1. Thermogravimetric analysis of G@Si/SiO₂ NPs/C, G@Si/SiO₂ layer/C and G@Si/C composites.

	Si (wt.%)	SiO ₂ (wt.%)	graphite (wt.%)	C (wt.%)
G@Si/SiO ₂ NPs/C	16.9	26.1	49.3	7.5
G@Si/SiO ₂ layer/C	15.2	30.4	47.4	7.0
G@Si/C	31.8	0	57.6	10.6
G@Si/SiO ₂ NPs/C-1	12.2	25.5	50.9	11.4
G@Si/SiO ₂ NPs/C-2	19.1	26.0	40.8	14.0
G@Si/SiO ₂ NPs/C-3	19.6	16.4	45.6	18.4
G@Si/SiO ₂ NPs/C-4	12.3	42.4	39.9	5.4

Table S2. Results summary for total intrusion volume, average pore diameter and porosity from mercury intrusion porosimetry (MIP).

	Total Intrusion Volume (mL g ⁻¹)	Average Pore Diameter (nm)	Porosity (%)
G@Si/SiO ₂ NPs/C	0.4542	121.3	52.6
G@Si/SiO ₂ layer/C	0.3311	155.4	46.3
G@Si/C	0.6258	168.6	56.4

Table S3. Electrochemical performances comparison of Si-graphite anode materials in LIBs.

Materials	Current (A g ⁻¹)	Capacity (mAh g ⁻¹)	Cycle Number	Retention (%)	Ref.
G@Si/SiO₂ NPs/C	0.2	~800	200	96	This work
	0.5	~600	800	92	
G@Si/SiO₂ layer/C	0.2	~800	200	88	
Si-nanolayer-embedded graphite/carbon	0.25	~500	100	96	1
Si/carbon/graphite	0.13	568	100	83.8	2
Si@O-MCMB/C	0.1	560	200	92.8	3
MCMB@Si@C	0.1	632	100	91.1	4
SGCpitch	0.25	523	50	97.5	5
Si/graphite/pyrolytic carbon	0.5	610	300	83.6	6
Silicon/carbon/natural graphite	0.1	471.5	100	87.9	7
Polymer-carbon coated Si-on- graphite	0.09	480	200	95	8
Si/pyrolyzed carbon@ graphite	0.1	550	100	93.75	9
Si/graphite/carbon	1	640	50	87.6	10
Si/C microspheres	0.3	~600	500	83.3	11

Reference

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